



# HER2001G thru HER2007G

Glass Passivated High Efficient Rectifiers  
Reverse Voltage 50 to 1000 Volts Forward Current 2.0 Amperes

## Features

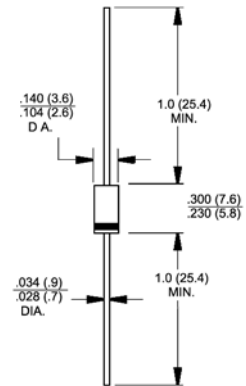
- ◆ Glass passivated chip
- ◆ Ultra fast switching for high efficiency
- ◆ Low reverse leakage current
- ◆ Low forward voltage drop
- ◆ High current capability
- ◆ Easily cleaned with Freon, Alcohol, Chlorothene and similar solvents
- ◆ Plastic material has UL flammability classification 94V-0



DO-204AC (DO-15)

## Mechanical Data

- ◆ Case : JEDEC DO-204AC(DO-15) molded plastic
- ◆ Polarity : Color band denotes cathode
- ◆ Weight : 0.014 ounce, 0.395 gram
- ◆ Mounting position : Any



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	HER 2001G	HER 2002G	HER 2003G	HER 2004G	HER 2005G	HER 2006G	HER 2007G	Units
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current @ $T_A=55^\circ\text{C}$	$I_{AV}$	2.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	60.0							Amps
Maximum forward voltage at 2.0A DC	$V_F$		1.0		1.3		1.7		Volts
Maximum DC reverse current @ $T_J=25^\circ\text{C}$ at rated DC blocking voltage @ $T_J=100^\circ\text{C}$	$I_R$				5.0				$\mu\text{A}$
					100				
Maximum reverse recovery time (Note 1)	$t_{rr}$		50				75		nS
Typical junction capacitance (Note 2)	$C_j$		30				15		pF
Typical thermal resistance (Note 3)	$R_{\theta JA}$	25							$^\circ\text{C/W}$
Operating junction temperature range	$T_J$	-55 to +150							$^\circ\text{C}$
Storage temperature range	$T_{STG}$	-55 to +150							$^\circ\text{C}$

- Notes:**
1. Test condition of  $T_m$ ;  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{RR}=0.25\text{A}$ .
  2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
  3. Thermal Resistance Junction to Ambient.

## RATINGS AND CHARACTERISTIC CURVES

FIG.1 - FORWARD CURRENT DERATING CURVE

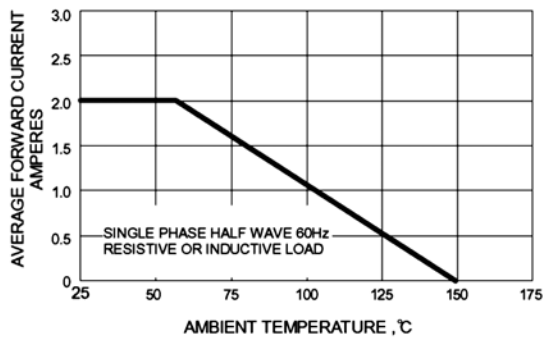


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

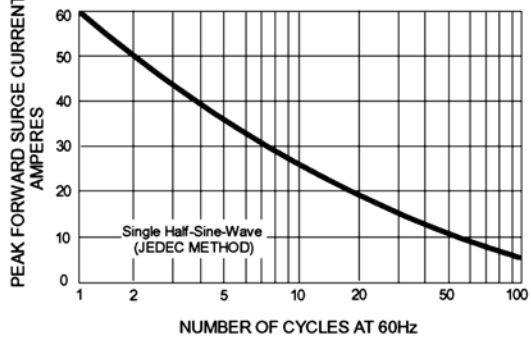


FIG.3 - TYPICAL JUNCTION CAPACITANCE

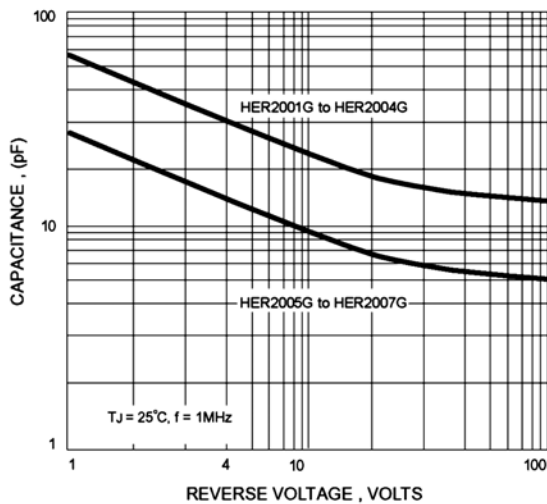


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

